

# **Fast Recovery Diode**

Replaces March 1998 version, DS4142-3.4

DS4142-4.0 January 2000

**KEY PARAMETERS** 

## **APPLICATIONS**

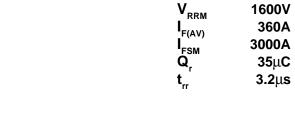
- Induction Heating
- A.C. Motor Drives
- Inverters And Choppers
- Welding
- High Frequency Rectification
- UPS

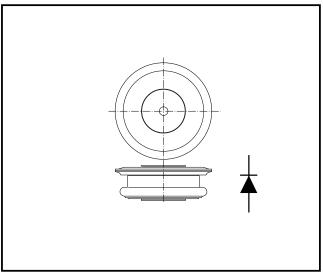
### **FEATURES**

- Double Side Cooling
- High Surge Capability
- Low Recovery Charge

### **VOLTAGE RATINGS**

Type Number	Repetitive Peak Reverse Voltage V <sub>RRM</sub> V	Conditions
DF252 16	1600	$V_{RSM} = V_{RRM} + 100V$
DF252 14	1400	KOW KKW
DF252 12	1200	
DF252 10	1000	
DF252 08	800	
DF252 06	600	





Outline type code: M771.
See Package Details for further information.

### **CURRENT RATINGS**

Symbol	Parameter	Conditions	Max.	Units		
Double Side Cooled						
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load, T <sub>case</sub> = 65°C	360	А		
I <sub>F(RMS)</sub>	RMS value	T <sub>case</sub> = 65°C	560	А		
I <sub>F</sub>	Continuous (direct) forward current	T <sub>case</sub> = 65°C	500	А		
Single Side	e Cooled (Anode side)					
I <sub>F(AV)</sub>	Mean forward current	Half wave resistive load, T <sub>case</sub> = 65°C	276	А		
I <sub>F(RMS)</sub>	RMS value	T <sub>case</sub> = 65°C	435	А		
I <sub>F</sub>	Continuous (direct) forward current	T <sub>case</sub> = 65°C	375	А		

# **DF252**

## **SURGE RATINGS**

Symbol	Parameter	Conditions	Max.	Units
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10ms half sine; with 09/ V T = 150°C	3.0	kA
l²t	I <sup>2</sup> t for fusing	10ms half sine; with 0% V <sub>RRM</sub> , T <sub>j</sub> = 150°C	45 x 10 <sup>3</sup>	A <sup>2</sup> s
I <sub>FSM</sub>	Surge (non-repetitive) forward current	10mg half sing; with 50% V T = 150%C	2.4	kA
l²t	I <sup>2</sup> t for fusing	10ms half sine; with 50% V <sub>RRM</sub> , T <sub>j</sub> = 150°C	28.8 x 10 <sup>3</sup>	A²s

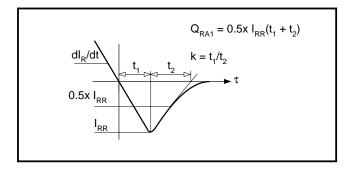
# THERMAL AND MECHANICAL DATA

Symbol	Parameter	Conditions		Min.	Max.	Units
$R_{th(j-c)}$	Thermal resistance - junction to case	Double side cooled	dc	-	0.07	°C/W
		Single side cooled	Anode dc	-	0.133	°C/W
			Cathode dc	-	0.147	°C/W
R <sub>th(c-h)</sub>	Thermal resistance - case to heatsink	Clamping force 3.5kN with mounting compound	Double side	-	0.02	°C/W
			Single side	-	0.04	°C/W
T <sub>vj</sub>	Virtual junction temperature	On-state (conducting)		-	150	°C
T <sub>stg</sub>	Storage temperature range			-55	150	°C
-	Clamping force			3.0	4.0	kN

## **CHARACTERISTICS**

Symbol	Parameter	Conditions	Тур.	Max.	Units
$V_{\scriptscriptstyle{\sf FM}}$	Forward voltage	At 450A peak, T <sub>case</sub> = 25°C	-	1.6	V
I <sub>RRM</sub>	Peak reverse current	At V <sub>RRM</sub> , T <sub>case</sub> = 125°C	-	20	mA
t <sub>rr</sub>	Reverse recovery time		3.2	-	μs
$Q_{RA1}$	Recovered charge (50% chord)	$I_{\rm F} = 750$ A, $di_{\rm RR}/dt = 100$ A/ $\mu$ s	-	35	μС
I <sub>RM</sub>	Reverse recovery current	$T_{case} = 125^{\circ}C, V_{R} = 100V$	-	21	А
K	Soft factor		1.5	-	-
$V_{TO}$	Threshold voltage	At T <sub>vj</sub> = 150°C	-	1.0	V
r <sub>T</sub>	Slope resistance	At T <sub>vj</sub> = 150°C	-	1.33	mΩ
$V_{FRM}$	Forward recovery voltage	di/dt = 1000A/μs, T <sub>j</sub> = 125°C	-	50	V

# DEFINITION OF K FACTOR AND $\mathbf{Q}_{\text{RA1}}$



## **CURVES**

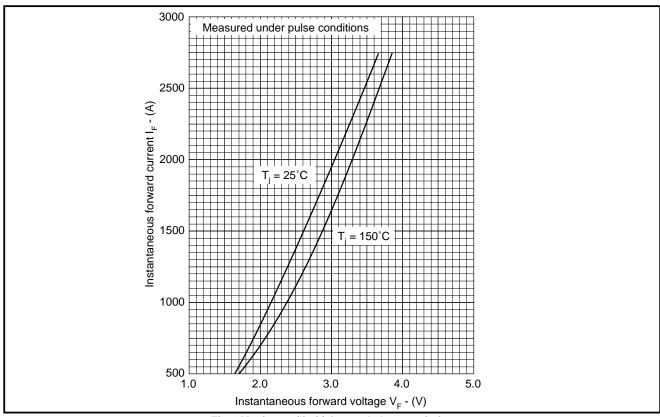


Fig.1 Maximum (limit) forward characteristics

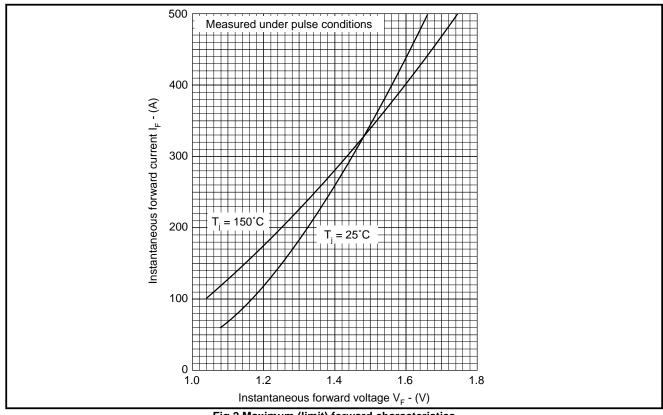


Fig.2 Maximum (limit) forward characteristics

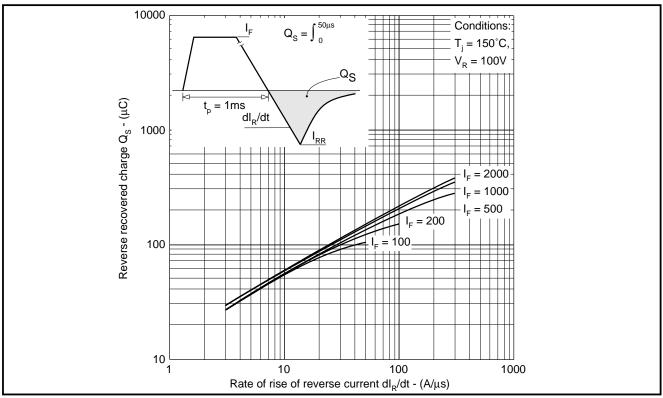


Fig.3 Recovered charge

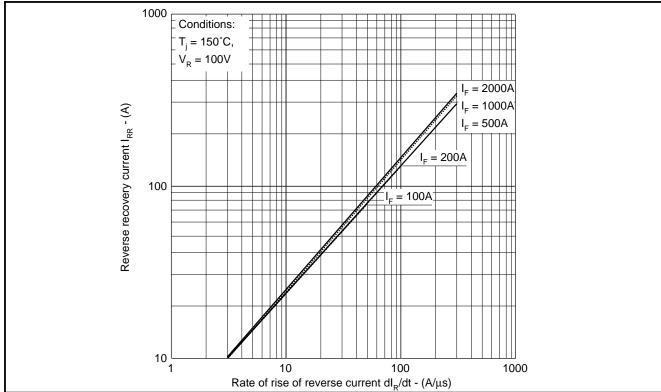


Fig.4 Typical reverse recovery current vs rate of fall of forward current

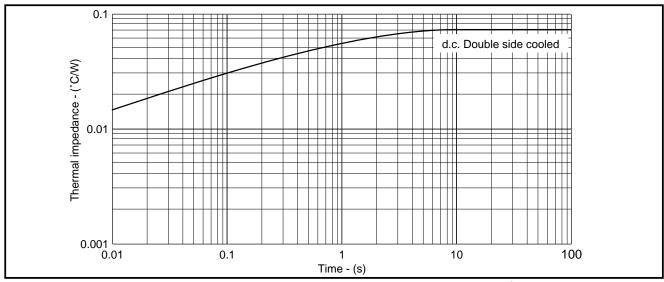
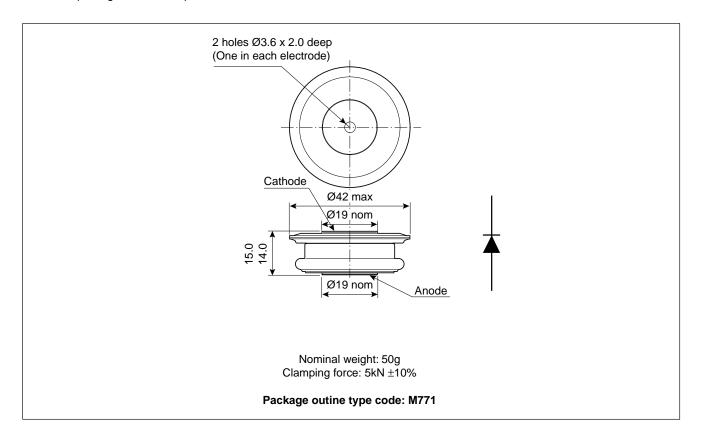


Fig.5 Maximum (limit) transient thermal impedance - junction to case - (°C/W)

### **PACKAGE DETAILS**

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.





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Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

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For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.



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